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ZXTN2018F 60V, SOT23, NPN medium power transistor

Summary

 $V_{(BR)CEV} > 140V, V_{(BR)CEO} > 60V$

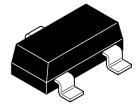
 $I_{C(cont)} = 5A$

 $R_{CE(sat)} = 25 \text{ m}\Omega \text{ typical}$

V_{CE(sat)} < 45 mV @ 1A

 $P_{D} = 1.2W$

Complementary part number: ZXTP2027F



Description

Advanced process capability and package design have been used to maximize the power handling and performance of this small outline transistor. The compact size and ratings of this device make it ideally suited to applications where space is at a premium.

Features

- · Higher power dissipation SOT23 package
- · High peak current
- · Low saturation voltage
- 140V forward blocking voltage

Applications

- · MOSFET and IGBT gate driving
- Motor drive
- · Relay, lamp and solenoid drive

C B

Pinout - top view

Ordering information

Device	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN2018FTA	7	8	3,000

Device marking

851

Absolute maximum ratings

Parameter	Symbol	Limit	Unit
Collector-base voltage	V _{CBO}	140	V
Collector-emitter voltage	V _{(BR)CEV}	140	V
Collector-emitter voltage	V _{CEO}	60	V
Emitter-base voltage	V _{EBO}	7	V
Peak pulse current	I _{CM}	12	А
Continuous collector current (a)	I _C	5	Α
Base current	I _B	1	А
Power dissipation @ T _A =25°C ^(a)	P _D	1.0	W
Linear derating factor		8.0	mW/°C
Power dissipation @ T _A =25°C (b)	P _D	1.2	W
Linear derating factor		9.6	mW/°C
Power dissipation @ T _A =25°C (c)	P _D	1.56	W
Linear derating factor		12.5	mW/ ^o C
Operating and storage temperature	T _j :T _{stg}	-55 to +150	°C

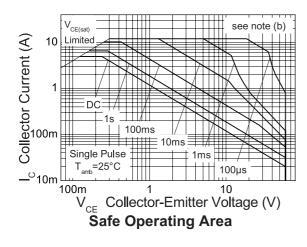
Thermal resistance

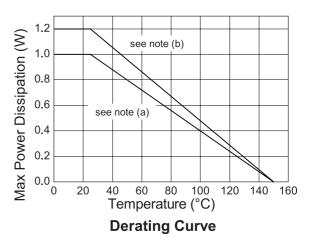
Parameter	Symbol	Value	Unit
Junction to ambient ^(a)	$R\Theta_{JA}$	125	°C/W
Junction to ambient ^(b)	$R\Theta_{JA}$	104	°C/W
Junction to ambient ^(c)	$R\Theta_{JA}$	80	°C/W

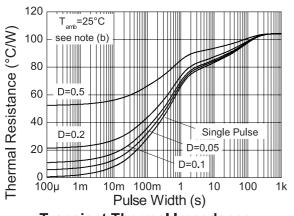
NOTES

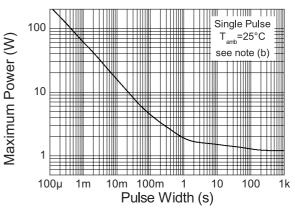
(a) Mounted on 18mm x 18mm X 1.6mm FR4 PCB with a very high coverage of 2 oz weight copper in still air conditions. (b) Mounted on 30mm x 30mm X 1.6mm FR4 PCB with a very high coverage of 2 oz weight copper in still air conditions. (c) as (b) above measured at t<5secs.

Characteristics

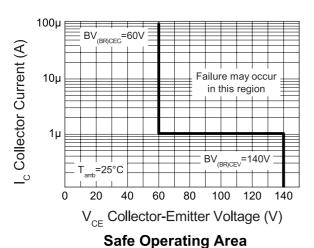








Transient Thermal Impedance



Pulse Power Dissipation

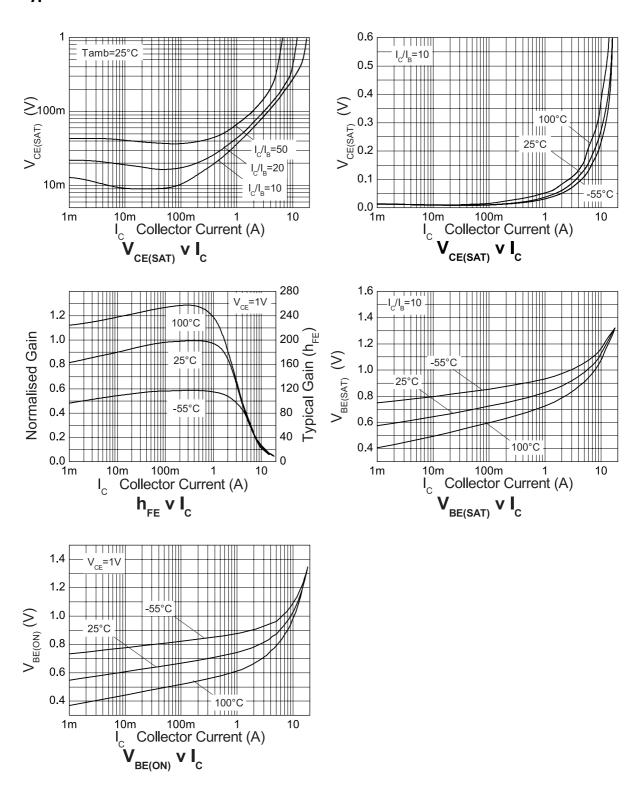
Electrical characteristics (at T_{amb} = 25°C unless otherwise stated)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	V _{(BR)CBO}	140	180		V	I _C =100μA
Collector-emitter breakdown voltage	V _{(BR)CEV}	140	180		V	$I_C = 1\mu A$, -1V < V_{BE} < +0.3V
Collector-emitter breakdown voltage	V _{(BR)CEO}	60	80		V	I _C =10mA ^(a)
Emitter-base breakdown voltage	V _{(BR)EBO}	7	8		V	I _E =100μA
Collector-emitter cut-off current	I _{CEV}		<1	20	nA	V _{CE} =110V, V _{BE} = -1V
Collector-base cut-off current	I _{CBO}		<1	20	nA	V _{CB} =110V
Emitter-base cut-off current	I _{EBO}		<1	10	nA	V _{EB} =6V
Static forward current transfer	H _{FE}	100	220			I _C =10mA, V _{CE} =1V ^(a)
ratio		100	200	300		I _C =2A, V _{CE} =1V ^(a)
		40	65			I _C =5A, V _{CE} =1V ^(a)
		15	25			I _C =10A, V _{CE} =1V ^(a)
Collector-emitter saturation	V _{CE(sat)}		15	30	mV	I _C =0.1A, I _B =5mA ^(a)
voltage			35	45	mV	I _C =1A, I _B =100mA ^(a)
			40	55	mV	I _C =1A, I _B =50mA ^(a)
			85	110	mV	I _C =2A, I _B =50mA ^(a)
			145	170	mV	I _C =5A, I _B =250mA ^(a)
			170	210	mV	I _C =6A, I _B =300mA ^(a)
Base-emitter saturation voltage	V _{BE(sat)}		0.92	1.00	V	I _C =5A, I _B =250mA ^(a)
Base-emitter turn-on voltage	V _{BE(on)}		0.85	0.95	V	I _C =5A, V _{CE} =1V ^(a)
Transition frequency	f _T	_	130		MHz	Ic=100mA, V _{CE} =10V, f=50MHz
Output capacitance	C _{obo}		28		pF	V _{CB} =10V, f=1MHz
Turn-on time	t _(on)		33		ns	V _{CC} =10V, I _C =1A,
Turn-off time	t _(off)		668		ns	I _{B1} =I _{B2} =100mA

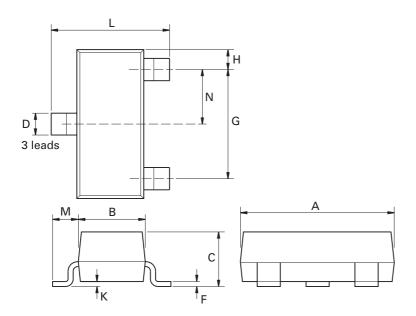
NOTES:

(a) Measured under pulsed conditions. Pulse width=300 $\mu S.$ Duty cycle $\leq\!2\%.$

Typical characteristics



Packaging details - SOT23



Dim.	m. Millimeters		Inches		Dim.	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Max.	Max.
Α	2.67	3.05	0.105	0.120	Н	0.33	0.51	0.013	0.020
В	1.20	1.40	0.047	0.055	K	0.01	0.10	0.0004	0.004
С	-	1.10	-	0.043	L	2.10	2.50	0.083	0.0985
D	0.37	0.53	0.015	0.021	М	0.45	0.64	0.018	0.025
F	0.085	0.15	0.0034	0.0059	N	0.95 NOM		0.0375 NOM	
G	1.90	NOM	0.075	NOM	-			-	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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